

DC COMPONENTS CO., LTD.

RECTIFIER SPECIALISTS

DL60P

TECHNICAL SPECIFICATIONS OF SMALL SIGNAL SCHOTTKY DIODES

FEATURES

- * Metal silicon junction, majority carrier conduction.
- * High current capability, low forward voltage drop.
- * Extremely low reverse current IR
- * Ultra speed switching characteristics
- * Small temperature coefficient of forward characteristics
- * Satisfactory Wave detection efficiency
- * For use in RECORDER, TV, RADIO, TELEPHONE as detectors, super high speed switching circuits, small current rectifier

MECHANICAL DATA

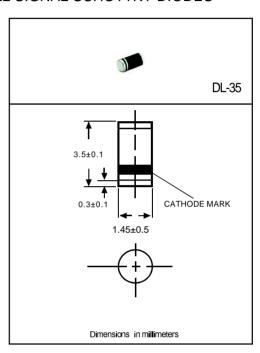
* Case: DL-35 glass case

* Polarity: color band denotes cathode end

* Weight: 0.05 grams approx.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



ABSOLUTE RATINGS(LIMITING VALUES)

PARAMETERS		SYMBOL	VALUE	UNITS
ZeneRepetitive Peak Reverse Voltage		VRRM	45	Volts
Forward Continuous Current	T _A =25°C	lF	50	mA
Peak Forward Surge Current(t=1S)		IFSM	500	mA
Storage and junction Temperature Range		T _{STG} /T _J	-65 to +125	°C
Maximum Lead Temperature for Soldering during 10S at 4mm from Case		TL	230	°C

ELECTRICAL CHARACTERISTICS

5.5	TEST CONDITIONS	SYMBOL	VALUE		
PARAMETERS	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward Voltage	l⊧=1 mA	VF	0.24	0.5	Volts
	l=200mA	VF	0.65	1.0	
Reverse Current	V _R =15V	lR	0.5	1.0	μΑ
Junction Capacitance	VR=10V f=1MHz	Cı	6.0		pF
Detection Efficiency	V _I =3V f=30MHz C _L =10pF R _L =3.8KΩ	η	60		%
Reverse Recovey time	F=IR=1mA Irr=1mA Rc=100Ω	trr		1	ns
Junction Ambient Thermal Resistance		RθJA	400		°C/W